## Low Voltage, 1 $\Omega$ Single SPDT Analog Switch (1:2 Multiplexer) with Power Down Protection

#### **DESCRIPTION**

The DG4157 is a high performance single pole double throw analog switch designed for 1.65 V to 5.5 V operation with single power rail.

Fabricated with high density CMOS technology, the device achieves low on resistance as 1  $\Omega$  at 4.5 V power supply and fast switching speed. The - 3 dB bandwidth is typically 117 MHz.

The DG4157 features break before make switch performance, and guarantees logic high control input threshold as low as 1.4 V over the range up to 5.5 V.

It can handle both analog and digital signals and permits signals with amplitudes of up to  $V_{CC}$  to be transmitted in either direction.

Power down protection circuit is built in to prevent abnormal current path through signal pins during power down condition.

Each output pin (A, B<sub>0</sub>, or B<sub>1</sub>) can withstand greater than 8 kV (human body model).

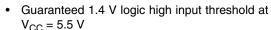
It is available in both SC-70-6 and miniQFN6 packages.

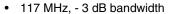
The features make it an ideal part for the switching of audio, video, and data stream.

SC-70-6L

#### **FEATURES**

- Direct cross of industry standard xxx4157
- 1.65 V to 5.5 V operation voltage range





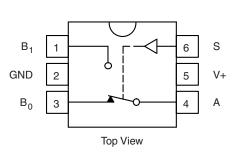
- Low on-resistance
- Power down protection
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

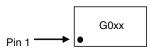


COMPLIANT HALOGEN

# **FREE**

#### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

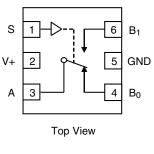


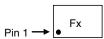


Device Marking: G0xx xx = Date/Lot Traceability Code

TRUTH TABLE					
Logic Input (S)	Function				
0	B <sub>0</sub> Connected to A				
1	B <sub>1</sub> Connected to A				

#### miniQFN-6L





Device Marking: Fx x = Date/Lot Traceability Code

ORDERING INFORMATION					
Temp. Range	Package	Part Number			
- 40 °C to 85 °C	SC-70-6L	DG4157DL-T1-GE3			
	miniQFN-6L	DG4157DN-T1-E4			



ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Reference V+ to GND		- 0.3 to + 6	V			
S, A, B <sup>a</sup>		- 0.3 to (V+ + 0.3)	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \			
Continuous Current (Any terminal)		± 200	mΛ			
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 400	mA			
Storage Temperature	D Suffix	- 65 to 150	°C			
Davier Dissipation (Daviers)	SC-70-6L <sup>c</sup>	250	mW			
Power Dissipation (Packages) <sup>b</sup>	miniQFN-6L <sup>d</sup>	160	11100			

#### Notes:

- a. Signals on A, or B or S exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 3.1 mW/°C above 70 °C.
- d. Derate 2 mW/°C above 70 °C.

SPECIFICATIONS							
		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 3 V, V_{IN} = 0 V \text{ or } V+^{e}$	Temp.a	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit
DC Characteristics							
		$V+ = 2.7 \text{ V}, B_0 \text{ or } B_1 = 1.5 \text{ V}, I_0 = 100 \text{ mA}$	Room		1.7	2.5	
On Resistance	R <sub>ON</sub>	, _0 e1 , .0	Full			3	
CTT TOOLSTATIO	014	$V+ = 4.5 \text{ V}, B_0 \text{ or } B_1 = 3.5 \text{ V}, I_0 = 100 \text{ mA}$	Room		0.95	1.2	
		, 0 1 , 3	Full			1.4	
On Resistance Flatness	B	$V+ = 2.7 \text{ V}, B_0 \text{ or } B_1 = 0.75 \text{ V}, 1.5 \text{ V},$ $I_0 = 100 \text{ mA}$	Room		0.2		Ω
On Resistance Flatness	R <sub>FLATNESS</sub>	$V+ = 4.5 \text{ V}, B_0 \text{ or } B_1 = 1 \text{ V}, 3.5 \text{ V},$	Room		0.14	0.3	
		$I_{O} = 100 \text{ mA}$	Full			0.4	
	ΔR <sub>ON</sub>	$V+ = 2.7 \text{ V}, B_0 \text{ or } B_1 = 1.5 \text{ V},$ $I_0 = 100 \text{ mA}$	Room		0.04		
On Resistance Match		$V+ = 4.5 \text{ V}, B_0 \text{ or } B_1 = 3.5 \text{ V},$	Room		0.05	0.12	
		$I_{O} = 100 \text{ mA}$	Full			0.15	
Switch Off Leakage Current	I <sub>OFF</sub>		Room	- 2		2	nA
		V+ = 5.5 V, A = 1 V, 4.5 V	Full	- 20		20	
Switch On Leakage Current		$B_0$ or $B_1 = 4.5$ V, 1 V or Floating	Room	- 4		4	
Switch On Leakage Current	'ON			- 40		40	1
Digital Control							
Input, High Voltage	V <sub>INH</sub>	V+ = 2.7 V to 5.5 V	Full	1.4			V
Input, Low Voltage	$V_{INL}$	VT = 2.7 V to 3.3 V	Full			0.4	]
Input Current	I <sub>INH</sub> , I <sub>INL</sub>	$V_{IN} = 0 \text{ or } V+$	Full	- 1		1	μΑ
Power Supply							
Power Supply Range	V+		Full	1.65		5.5	V
Quiescent Supply Current	l+	V+ = 5.5 V, V <sub>IN</sub> = 0 V, 5.5 V	Room		0.05	0.5	μΑ
Quicocent ouppry ounent	IT	• 1 - 0.0 •, • IN - 0 •, 0.0 •	Full			1	μΛ





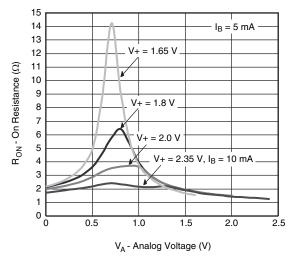
SPECIFICATIONS							
		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 3 V, V_{IN} = 0 V or V+^{e}$	Temp.a	Min.b	Typ. <sup>c</sup>	Max.b	Unit
AC Characteristics							
		V+ = 2.7 V, $B_0$ or $B_1$ = 1.5 V, $R_L$ = 50 $Ω$ ,	Room		40	55	
Turn-On Time <sup>d</sup>	t <sub>ON</sub>	$C_L = 35 pF$	Full			60	1
ium-on time	ON	$V+ = 4.5 \text{ V}, B_0 \text{ or } B_1 = 1.5 \text{ V}, R_L = 50 \Omega,$	Room		22	37	
		$C_L = 35 pF$	Full			40	
		V+ = 2.7 V, $B_0$ or $B_1$ = 1.5 V, $R_L$ = 50 Ω,	Room		12	27	ns
Turn-Off Time <sup>d</sup>	t <sub>OFF</sub>	$C_L = 35 pF$	Full			30	
ium-on rime		$V+ = 4.5 \text{ V}, B_0 \text{ or } B_1 = 1.5 \text{ V}, R_L = 50 \Omega,$	Room		8	23	113
		$C_L = 35 pF$	Full			25	
D 1 D ( M ) T: d	<b>t</b>	V+ = 2.7 V, B <sub>0</sub> = B <sub>1</sub> = 1.5 V, R <sub>L</sub> = 50 Ω, $C_L$ = 35 pF	Room	1	26		
Break-Before-Make Time <sup>d</sup>	t <sub>BBM</sub>	V+ = 4.5 V, B <sub>0</sub> = B <sub>1</sub> = 1.5 V, R <sub>L</sub> = 50 Ω, $C_L$ = 35 pF	HOOM	1	15		
Charge Injection <sup>d</sup>	Q	$C_L = 1 \text{ nF, } R_{GEN} = 0 \Omega, V_{GEN} = 0 V$	Room		50		рC
O((1 + 1) d	OIRR	$R_L = 50 \Omega$ , $f = 1 MHz$	Room		- 58		- dB
Off Isolation <sup>d</sup>	OIRR	$R_L$ = 50 Ω, f = 10 MHz	Hoom		- 31		
0	V	$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF, f = 1 MHz	D		- 63		
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 10 MHz$	Room		- 36		
Bandwidth <sup>d</sup>	BW	R <sub>L</sub> = 50 Ω	Room		117		MHz
Total Harmonic Distortion <sup>d</sup>	THD	$R_L$ = 600 $\Omega$ , $V_{IN}$ = 0.5 V, f = 20 to 20 kHz	Room		0.02		%
Capacitance						_	
BX Port Off Capacitanced	C <sub>B(OFF)</sub>				20		
A Port On Capacitance <sup>d</sup>	C <sub>A(ON)</sub>	$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF, f = 1 MHz	Room		57		pF
Control Pin Capacitanced	C <sub>IN</sub>				5		1

- a. Room = 25  $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e.  $V_{IN}$  = input voltage to perform proper function.

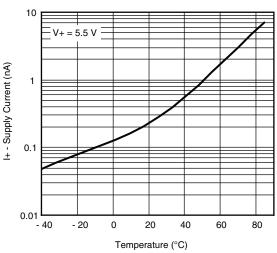
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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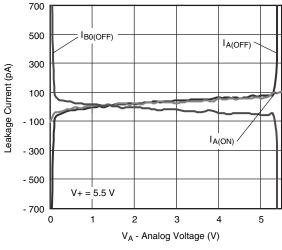
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



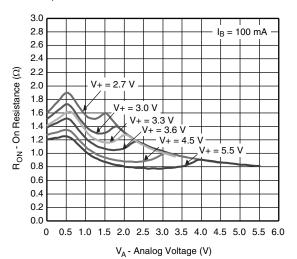
 $\rm R_{ON}$  vs.  $\rm V_A$  and Supply Voltage



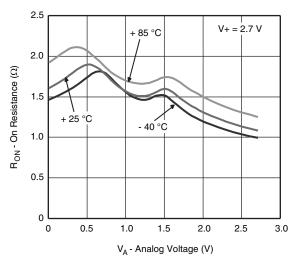
**Supply Current vs. Temperature** 



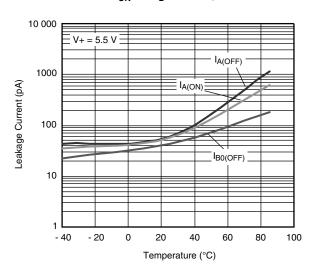
Leakage vs. Analog Voltage



R<sub>ON</sub> vs. V<sub>A</sub> and Supply Voltage



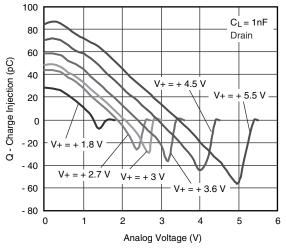
R<sub>ON</sub> vs. V<sub>D</sub> and Temperature



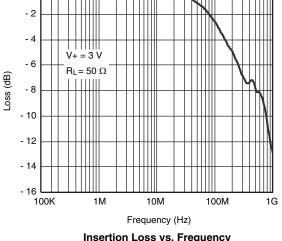
Leakage Current vs. Temperature



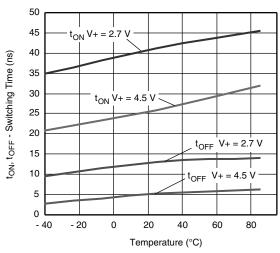
## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



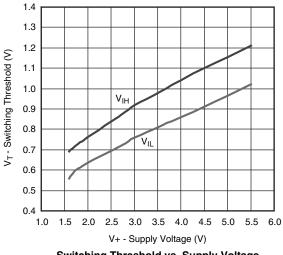
Charge Injection vs. Analog Voltage



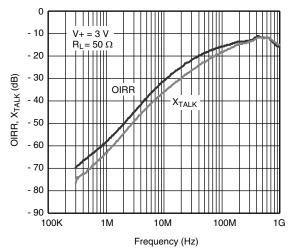
Insertion Loss vs. Frequency



Switching Time vs. Temperature



Switching Threshold vs. Supply Voltage



Off-Isolation and Crosstalk vs. Frequency

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#### **TEST CIRCUITS**

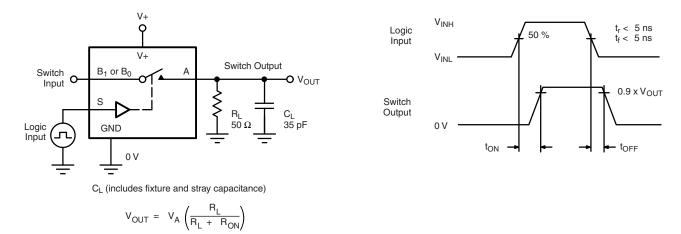


Figure 1. Switching Time

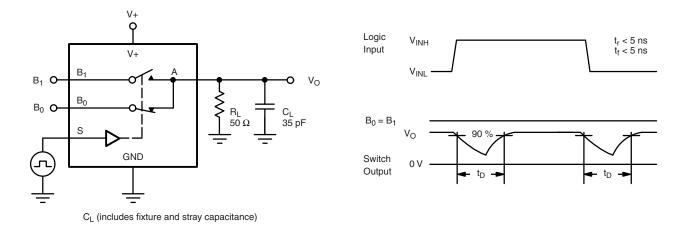


Figure 2. Break-Before-Make Interval

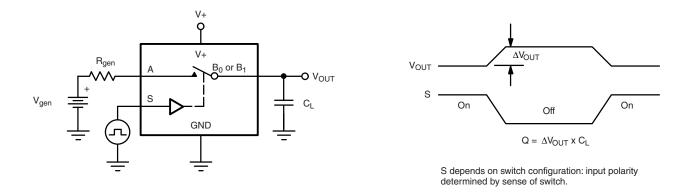


Figure 3. Charge Injection



#### **TEST CIRCUITS**

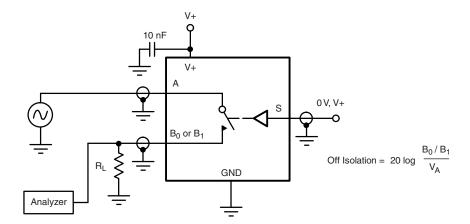


Figure 4. Off-Isolation

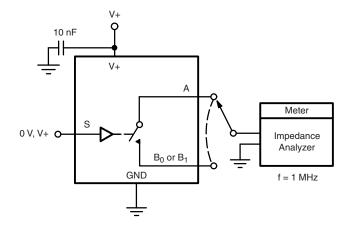


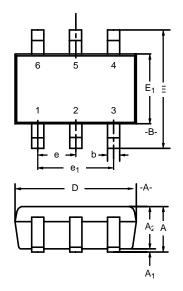
Figure 5. Channel Off/On Capacitance

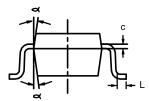
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## SC-70: 6-LEADS



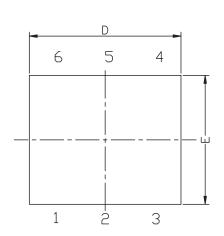


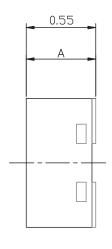
Min 0.90 - 0.80	Nom - -	<b>Max</b> 1.10 0.10	<b>Min</b> 0.035	Nom -	Max
_	-		0.035	-	0.042
- 0.80	-	0.10		1	0.043
0.80			_	1	0.004
	-	1.00	0.031	1	0.039
0.15	-	0.30	0.006	-	0.012
0.10	_	0.25	0.004	-	0.010
1.80	2.00	2.20	0.071	0.079	0.087
1.80	2.10	2.40	0.071	0.083	0.094
1.15	1.25	1.35	0.045	0.049	0.053
0.65BSC				0.026BSC	;
1.20	1.30	1.40	0.047	0.051	0.055
0.10	0.20	0.30	0.004	0.008	0.012
7°Nom				7°Nom	
	0.10 1.80 1.80 1.15 1.20 0.10	0.10	0.10 - 0.25  1.80 2.00 2.20  1.80 2.10 2.40  1.15 1.25 1.35  0.65BSC  1.20 1.30 1.40  0.10 0.20 0.30  7°Nom	0.10	0.10         -         0.25         0.004         -           1.80         2.00         2.20         0.071         0.079           1.80         2.10         2.40         0.071         0.083           1.15         1.25         1.35         0.045         0.049           0.65BSC         0.026BSC         0.026BSC           1.20         1.30         1.40         0.047         0.051           0.10         0.20         0.30         0.004         0.008           7°Nom         7°Nom           946—Rev. B, 09-Jul-01

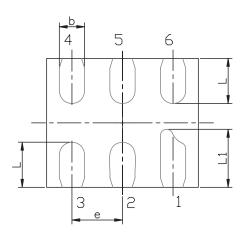
DWG: 5550

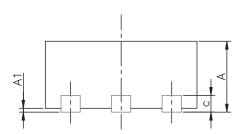


## MINI QFN-6L CASE OUTLINE







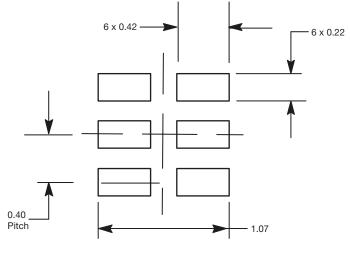


DIM	MILLIMETERS			INCHES			
DIIVI	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.	
Α	0.50	0.55	0.60	0.0197	0.0217	0.0236	
A1	0.00	-	0.05	0.000	-	0.002	
b	0.15	0.20	0.25	0.006 0.008 0.010			
С		0.15 REF			0.006 REF		
D	1.15	1.20	1.25	0.045 0.047 0.049			
E	0.95	1.00	1.05	0.037	0.039	0.041	
е		0.40 BSC		0.016 BSC			
L	0.30	0.35	0.40	0.012	0.014	0.016	
L1	0.40	0.45	0.50	0.016	0.018	0.020	

ECN T-07039-Rev. A, 12-Feb-07 DWG: 5958



### **RECOMMENDED MINIMUM PADS FOR MINI QFN 6L**



Mounting Footprint Dimensions in mm



## **Legal Disclaimer Notice**

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Revision: 02-Oct-12 Document Number: 91000